

Fixed Attenuator Chip

- ◆ DC to 26.5 GHz
- ◆ 1 dB
- ◆ 200mW

Features

- Thin film
- High attenuation accuracy
- Small VSWR
- Ceramic chip: 99% alumina
- Laser trimmed
- Low cost-high performance

Model No. Description

FACXXXXX

X - Soldering method A or B

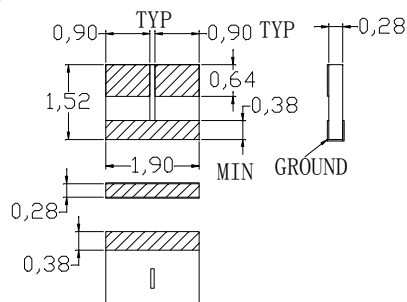
XX- attenuation: **dB.

XX- frequency range 06: DC to 6GHz
 10: DC to 10GHz
 12: DC to 12.4GHz
 18: DC to 18GHz
 26: DC to 26.5GHz.

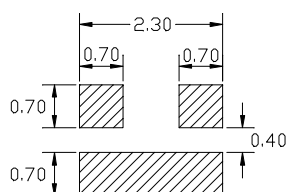
Soldering method A: The gold terminals in this series are just designed to use wire-bonding application.

Soldering method B: The gold terminals in this series are just designed to use lead free reflow application.

Package Outlines



Recommended Layout



Note: all dimensions shown in mm

Specifications

| | |
|---------------------------------|--|
| Frequency Range | DC to 26.5 GHz |
| Attenuation | 1 dB |
| Attenuation Accuracy (Typical.) | ±0.5 dB DC to 8.5GHz + 0.5 dB 8.5 to 12.4 GHz + 0.5 dB 12.4 to 18 GHz + 1.0 dB 18 to 26.5 GHz |
| Attenuation Stability | 0.0001 dB/dB/°C |
| Nominal Impedance | 50 Ohm |
| Rated Input Power | 200mW |
| Operating Temperature | -55 °C to +150 °C |

| FREQ. RANGE (GHz) | VSWR(:1) Typical |
|-------------------|------------------|
| DC to 8.5 | 1.05 |
| 8.5 to 12.4 | 1.10 |
| 12.4 to 18 | 1.15 |
| 18 to 26.5 | 1.40 |

Material Specification

| | |
|-----------|---|
| substrate | 99% alumina |
| terminal | Gold over Tiw Gold thickness : 3 μ m |
| resistor | Tantalum nitride thin film |

Average Power Derating Curve

